



Supplementary Materials

In Situ and Ex Situ Characterization of the Microstructure Formation in Ni-Cr-Si Alloys during Rapid Solidification – toward Alloy Design for Laser Additive Manufacturing

Table S1. List of Crystallographic Parameters of Phases Referred in Present Work [Liu, X., et al.: Experimental Investigation of Phase Equilibria in the Ni-Cr-Si Ternary System. J. Phase Equilibria Diffus. 35, 334–342 (2014); Gupta, K.P.: The Cr-Ni-Si (Chromium-Nickel-Silicon) System. J. Phase Equilibria Diffus. 27, 523–528 (2006).].

Phase	Туре	Pearson Symbol	Space Group	a [Å]	<i>b</i> [Å]	c [Å]	β [°]
(Ni)	Cu	cF4	Fm-3m	3.552	_	_	90
β ₁ -Ni ₃ Si	AuCu ₃	cP4	Pm-3m	3.50	_	_	90
β ₃ -Ni ₃ Si	—	mC16	-	7.04	6.26	5.08	48.84
γ -Ni ₃₁ Si ₁₂	$Ni_{31}Si_{12}$	hP43	P321	6.67	_	12.28	90
δ-Ni ₂ Si	Co ₂ Si	oP12	Pnma	7.06	4.99	3.72	90
σ-Cr ₁₃ Ni ₅ Si	σ(Cr,Fe)	tP30	P42/mnm	8.787	_	4.570	90
π -Cr ₃ Ni ₅ Si ₂	AlAu ₄	cP20	P213	6.120	_	_	90
τ -Cr ₆ Ni ₁₆ Si ₇	Mg ₆ Cu ₁₆ Si ₇	cF116	Fm-3m	11.10	_	_	90

Table S2. Table of relevant invariant reactions [Schuster, J.C., Du, Y.: Experimental investigation and thermodynamic modeling of the Cr-Ni-Si system. Metall. Mater. Trans. A. 31, 1795–1803 (2000)].

Ni-Si	Ni-Cr-Si			
e7: $L \leftrightarrow \theta + \delta$ -Ni ₂ Si,	E1: L \leftrightarrow Cr ₃ Si + γ -Ni ₃₁ Si ₁₂ + δ -Ni ₂ Si			
T = 1240 °C	T = 1138 °C			
e9: $L \leftrightarrow (Ni) + \beta_3 - Ni_3Si$,	E2: $L \leftrightarrow (Ni) + \pi$ -Cr ₃ Ni ₅ Si ₂ + γ -Ni ₃₁ Si ₁₂			
T = 1151 °C	$T = 1082 \ ^{\circ}C$			
p5: L + γ-Ni ₃₁ Si ₁₂ ↔ $β_3$ -Ni ₃ Si,	U6: L + Cr ₃ Si $\leftrightarrow \gamma$ -Ni ₃₁ Si ₁₂ + τ_1			
T = 1199 °C	T = 1126 °C			
	U8: L + β_{2} - \leftrightarrow (Ni) + γ -Ni ₃₁ Si ₁₂			
	T = 1119 °C			
	U9: $L + \tau_1 \leftrightarrow \gamma$ -Ni ₃₁ Si ₁₂ + π -Cr ₃ Ni ₅ Si ₂			
-	$T = 1088 \ ^{\circ}C$			



Figure S1. 2D pattern of amorphous ring of hot melt at t = 4005 ms (left image) and diffraction spots of solidified crystals (right image) at t = 4029 ms in the Ni14Cr12Si alloy.